

Title (en)
FLUID ASSISTED CRYOGENIC CLEANING

Title (de)
FLUIDUNTERSTÜTZTE KRYOGENE REINIGUNG

Title (fr)
NETTOYAGE CRYOGENIQUE ASSISTE PAR FLUIDE

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Application
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- US 40314703 A 20030331

Abstract (en)
[origin: WO03086668A1] The present invention is directed to fluid assisted cryogenic cleaning of a substrate surface requiring precision cleaning such as semiconductors, metals, and dielectric films. The process comprises the steps of applying a fluid selected from the group consisting of high vapor pressure liquids, reactive gases, and vapors of reactive liquids onto the substrate surface followed by or simultaneously with cryogenic cleaning of the substrate surface to remove contaminants.

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Citation (search report)

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- See references of WO 03086668A1

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DOCDB simple family (publication)
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